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## **Electronic Supplementary Information**

## Sn<sub>14</sub>O<sub>11</sub>Br<sub>6</sub>: A promising birefringent material with [Sn<sub>14</sub>O<sub>11</sub>Br<sub>6</sub>] layer

Zixiu Lu,<sup>a,b</sup> Fangfang Zhang,<sup>a,b,\*</sup> Abudukadi Tudi,<sup>a,b</sup> Zhihua Yang,<sup>a,b</sup> Zijian Li<sup>a,b</sup> and

Shilie Pan<sup>a,b,\*</sup>

<sup>a</sup>CAS Key Laboratory of Functional Materials and Devices for Special Environments;

Xinjiang Technical Institute of Physics & Chemistry, CAS; Xinjiang Key Laboratory

of Electronic Information Materials and Devices, 40-1 South Beijing Road, Urumqi

830011, China.

<sup>b</sup>Center of Materials Science and Optoelectronics Engineering, University of Chinese

Academy of Sciences, Beijing 100049, China.

\*Corresponding authors: ffzhang@ms.xjb.ac.cn; slpan@ms.xjb.ac.cn.

Atoms	x	У	Z	$U_{(eq)}^{*}$
Sn1	7363(1)	902(1)	7474(1)	15(1)
Sn2	5645(1)	7944(1)	7486(1)	16(1)
Sn3	1691(1)	9127(1)	7497(1)	15(1)
Sn4	335(1)	6195(1)	7538(1)	16(1)
Sn5	8552(1)	3693(1)	7466(1)	14(1)
Sn6	3117(1)	2228(1)	7536(1)	14(1)
Sn7	4263(1)	5364(1)	6675(1)	20(1)
Sn8	4622(1)	4682(1)	8325(1)	21(1)
Sn9	1782(1)	3042(1)	9290(1)	20(1)
Sn10	8338(1)	2708(1)	5721(1)	18(1)
Sn11	9052(1)	1275(1)	9211(1)	18(1)
Sn12	12880(1)	3(1)	5730(1)	20(1)
Sn13	11090(1)	4503(1)	5791(1)	18(1)
Sn14	3622(1)	8507(1)	9256(1)	18(1)
01	3821(5)	8146(5)	8213(2)	15(1)
O2	5904(5)	5451(5)	7487(2)	12(1)
03	10792(5)	2318(5)	5969(2)	17(1)
O4	3514(5)	8766(5)	6779(2)	15(1)
05	1961(5)	3918(5)	8248(2)	14(1)
06	1458(5)	11025(5)	9024(2)	16(1)
O7	4882(5)	3117(5)	7505(2)	14(1)
08	2566(5)	6470(5)	7507(2)	13(1)
09	7722(6)	2679(5)	6757(2)	16(1)
O10	8064(5)	2051(5)	8181(2)	15(1)
011	1641(5)	4500(5)	6819(2)	15(1)
Br1	5541(1)	10258(1)	9032(1)	24(1)
Br2	10019(1)	-993(1)	5972(1)	24(1)
Br3	-1868(1)	5030(1)	9021(1)	25(1)
Br4	7467(1)	6426(1)	5979(1)	25(1)
Br5	10666(1)	-2299(1)	9016(1)	24(1)
Br6	14803(1)	1628(1)	5977(1)	25(1)

**Table S2.** Atomic coordinates and equivalent isotropic displacement parameterfor  $Sn_{14}O_{11}Br_6$ .

 $U_{(eq)}^*$  is defined as one third of the trace of the orthogonalized  $U_{ij}$  tensor.

Table 55. Beleeted			[D1 <sub>6</sub> .
Sn1-O9	2.139(4)	Sn8-O8	2.226(4)
Sn1-O10	2.133(4)	Sn8-O2	2.239(4)
Sn1-O7	2.180(4)	Sn8-O7	2.242(4)
Sn2-O4	2.131(4)	Sn9-O5	2.104(4)
Sn2-O1	2.143(4)	Sn9-O6 <sup>#1</sup>	2.153(4)
Sn2-O2	2.183(4)	Sn9-Br3	2.912(9)
Sn3-O4	2.107(4)	Sn10-O9	2.094(4)
Sn3-O1	2.115(4)	Sn10-O3	2.145(4)
Sn3-O8	2.155(4)	Sn10-Br2	2.910(8)
Sn4-O11	2.147(4)	Sn11-O10	2.074(4)
Sn4-O5	2.135(4)	Sn11-O6 <sup>#2</sup>	2.141(4)
Sn4-O8	2.186(4)	Sn11-Br5	2.942(8)
Sn5-O9	2.113(4)	Sn12-O4#4	2.111(4)
Sn5-O10	2.111(4)	Sn12-O3	2.155(4)
Sn5-O2	2.152(4)	Sn12-Br6	2.907(8)
Sn6-O5	2.112(4)	Sn13-O11#3	2.067(4)
Sn6-O11	2.113(4)	Sn13-O3	2.138(4)
Sn6-O7	2.146(4)	Sn13-Br4	2.943(8)
Sn7-O7	2.245(4)	Sn14-O1	2.101(4)
Sn7-O8	2.233(4)	Sn14-O6	2.150(4)
Sn7-O2	2.229(4)	Sn14-Br1	2.916(8)
O9-Sn1-O7	82.96(16)	O2-Sn8-O7	75.22(14)
O10-Sn1-O7	82.17(16)	O8-Sn8-O2	75.26(15)
O10-Sn1-O9	79.56(15)	O8-Sn8-O7	75.59(14)
O1-Sn2-O2	82.27(15)	O5-Sn9-O6#1	93.30(16)
O4-Sn2-O1	80.16(16)	O5-Sn9-Br3	88.19(12)
O4-Sn2-O2	82.59(15)	O6 <sup>#1</sup> -Sn9-Br3	83.40(11)
O1-Sn3-O8	83.09(15)	O3-Sn10-Br2	84.74(11)
O4-Sn3-O1	81.36(16)	O9-Sn10-O3	93.97(17)
O4-Sn3-O8	84.11(16)	O9-Sn10-Br2	88.84(11)
O5-Sn4-O8	82.83(15)	O6 <sup>#2</sup> -Sn11-Br5	84.82(11)
O5-Sn4-O11	79.70(15)	O10-Sn11-O6 <sup>#2</sup>	96.98(16)

Table S3. Selected bond lengths [Å] and angles [deg] for  $Sn_{14}O_{11}Br_6$ .

Symmetry transformations used to generate equivalent atoms:



**Figure S1** (a)  $[Sn_4O_2F_4]$  infinite chains of  $Sn_2(SnOF_2)_2$ ; (b) 3D  $[Sn_4OF_6]$  framework of  $Sn_4OF_6$ ; (c)  $[Sn_{14}O_8Cl_{10}]$  infinite chains of  $Sn_7O_4Cl_6$ ; (d) 3D  $[Sn_7O_4Br_6]$  framework of  $Sn_7O_4Br_6$ ; (e) 3D  $[Sn_4OI_6]$  framework of  $Sn_4OI_6$ .



Figure S2 EDX analysis of Sn<sub>14</sub>O<sub>11</sub>Br<sub>6</sub>.









Figure S5 Powder XRD patterns of  $Sn_{14}O_{11}Br_6$  at 420, 520, 530 and 550 °C, respectively.



**Figure S6** (a) A plate-shaped TOB crystal with a thickness of 6.965  $\mu$ m; (b) The interference color of TOB crystal under the polarizing microscope; The TOB crystal in the left (c) and right (d) subtraction position.



Figure S7 Electron localization function diagrams of the Sn-O/Br polyhedra in TOB.